

PST ZP609LT**WELDING DIODE****Features**

- Blocking Capability up to 400 V
- High Surge Rating
- Rugged Ceramic Hermetic Package

ELECTRICAL CHARACTERISTICS AND RATINGS**Blocking**

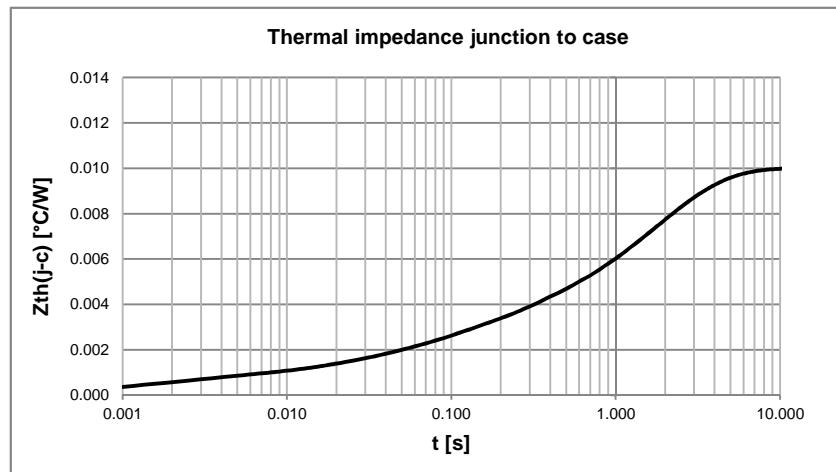
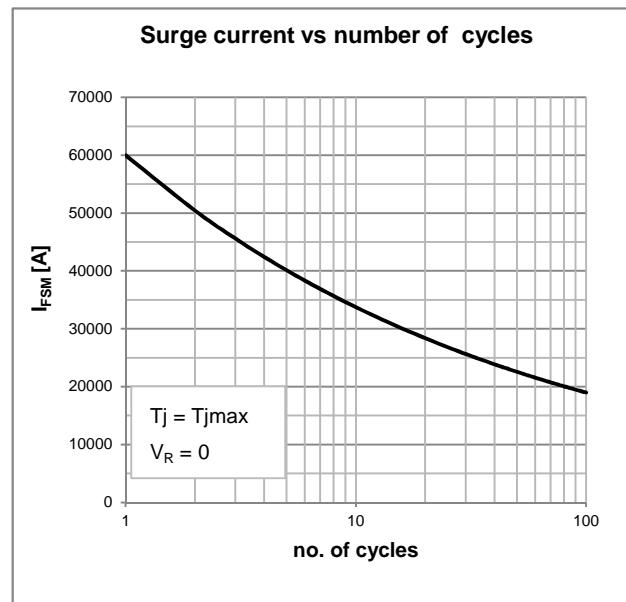
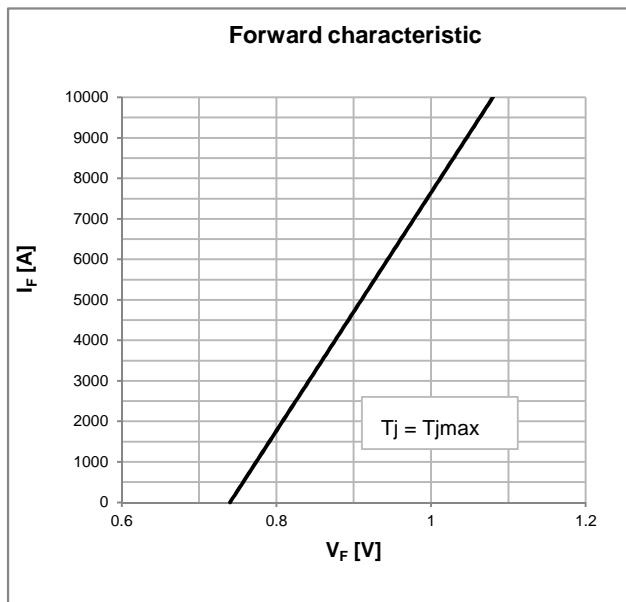
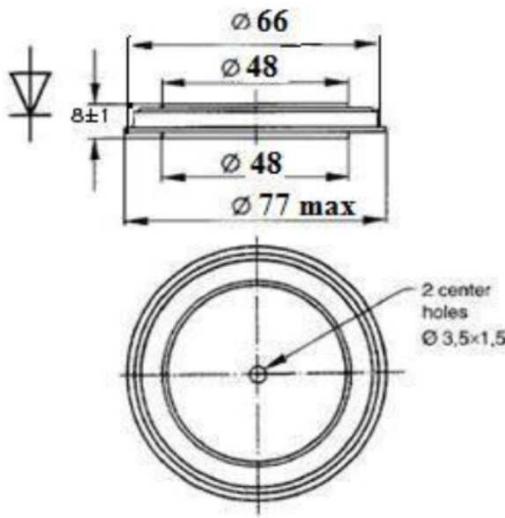
Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Repetitive peak reverse voltage	V_{RRM}		400		V	$T_j = -40 \text{ }^\circ\text{C} \text{ to } 190 \text{ }^\circ\text{C}$
Non repetitive peak reverse voltage	V_{RSM}		500		V	$T_j = -40 \text{ }^\circ\text{C} \text{ to } 190 \text{ }^\circ\text{C}$
Repetitive peak reverse current	I_{RRM}		60		mA	$T_j = T_{jmax}, V = V_{RRM}$

Conducting

Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Average value of forward current	$I_{F(AV)}$		7590		A	50 Hz sinewave, 180° conduction, $T_c = 85 \text{ }^\circ\text{C}$
RMS value of forward current	$I_{F(RMS)}$		11200		A	50 Hz sinewave, 180° conduction, $T_c = 85 \text{ }^\circ\text{C}$
Peak one cycle surge (non repetitive) current	I_{FSM}		60		kA	50 Hz sinewave, 180° conduction, $T_j = T_{jmax}, V_R = 0$
$I^2 t$	$I^2 t$		18000		kA ² s	$T_j = T_{jmax}$
Peak forward voltage	V_{FM}		0.90		V	Forward current 4500 A, $T_j = T_{jmax}$
Threshold voltage	$V_{F(TO)}$		0.74		V	$T_j = T_{jmax}$
Forward slope resistance	r_F		0.034		mΩ	$T_j = T_{jmax}$

Thermal and mechanical characteristics and ratings

Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Operating temperature	T_j	-40	190		°C	
Storage temperature	T_{stg}	-40	190		°C	
Thermal resistance junction to case	$R_{th(j-c)}$		0.010		°C/W	Double side cooled, 180° SIN
Thermal resistance case to sink	$R_{th(c-s)}$		0.004		°C/W	Mounting surfaces smooth, flat and greased
Mounting force	F	19	26		kN	
Weight	W			200	g	

PST ZP609LT**WELDING DIODE****OUTLINE AND DIMENSIONS**

- All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink surfaces with flatness < 0.03 mm and roughness < 2µm